



Vishay Semiconductors

PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS		
Maximum average on-state current	I _{T(AV)}	$T_{C} = 79 \text{ °C}, 180^{\circ} conduction half sine wave$	35			
Maximum continuous RMS on-state current as AC switch	I _{T(RMS)}		55	А		
Maximum peak, one-cycle	L	10 ms sine pulse, rated V_{RRM} applied		420		
non-repetitive surge current	I _{TSM}	10 ms sine pulse, no voltage reapplied		500		
Maximum I ² t for fusing	l ² t	10 ms sine pulse, rated V_{RRM} applied	Initial T _J = T _{.1} maximum	880	A ² s	
Maximum -t for fusing	I-t	10 ms sine pulse, no voltage reapplied	1250	A-S		
Maximum I ² √t for fusing	l²√t	t = 0.1 to 10 ms, no voltage reapplied	12 500	A²√s		
Low level value of threshold voltage	V _{T(TO)1}		1.02	V		
High level value of threshold voltage	V _{T(TO)2}	T _J = 125 °C	1.23			
Low level value of on-state slope resistance	r _{t1}	$I_{\rm J} = 125$ C	9.74	mΩ		
High level value of on-state slope resistance	r _{t2}			7.50	1112.2	
Maximum peak on-state voltage	V _{TM}	110 A, T _J = 25 °C		1.85	V	
Maximum rate of rise of turned-on current	dl/dt	$T_J = 25 \ ^{\circ}C$		100	A/μs	
Maximum holding current	Ι _Η	Anode supply = 6 V, resistive load, initial I_T	200			
Maximum latching current	١L	Anode supply = 6 V, resistive load, $T_J = 25$	300			
	1 /1	$T_J = 25 ^{\circ}C$	0.5	mA		
Maximum reverse and direct leakage current	I _{RRM} /I _{DRM}	$T_J = 125 \text{ °C}$ $V_R = Rated V_{RRM}/V_D$	V _R = Rated V _{RRM} /V _{DRM}			
Maximum rate of rise of off-state voltage	dV/dt	$T_J = T_J$ maximum, linear to 80 % V _{DRM} , R_q	1000	V/µs		

TRIGGERING									
PARAMETER	SYMBOL	TE	VALUES	UNITS					
Maximum peak gate power	P _{GM}			10	W				
Maximum average gate power	P _{G(AV)}								
Maximum peak gate current	I _{GM}			2.5	А				
Maximum peak negative gate voltage	- V _{GM}			10					
		T _J = - 40 °C		4.0	V				
Maximum required DC gate voltage to trigger	V_{GT}	T _J = 25 °C	Anode supply = 6 V resistive load	2.5					
		T _J = 125 °C		1.7					
		T _J = - 40 °C		270					
Maximum required DC gate aurrent to triager	I	$T_J = 25 \text{ °C}$ Anode supply = 6 V resistive load	150						
Maximum required DC gate current to trigger	I _{GT}	T _J = 125 °C		80	mA				
		$T_{\rm J} = 25 \ ^{\circ}{\rm C}$, for 40	40						
Maximum DC gate voltage not to trigger	V_{GD}	T 105 °C V	0.25	V					
Maximum DC gate current not to trigger	I _{GD}	1J = 123 C, VDRM	$T_J = 125 \text{ °C}, V_{DRM} = \text{Rated value}$						

VS-40TPS16PbF, VS-40TPS16-M3



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THERMAL AND MECHANICAL SPECIFICATIONS										
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS					
Maximum junction and storage temperature range		T _J , T _{Stg}		-40 to 125	°C					
Maximum thermal resistance, junction to case		R _{thJC}	R _{thJC} DC operation							
Maximum thermal resistance, junction to ambient		R _{thJA}		40	°C/W					
Maximum thermal resistance, case to heatsink		R _{thCS}	Mounting surface, smooth and greased	0.2						
Approvimato weight				6	g					
Approximate weight				0.21	oz.					
Mounting torque	minimum			6 (5)	kgf ⋅ cm					
	maximum			12 (10)	(lbf ⋅ in)					
Marking device			Case style TO-247AC	40TF	PS16					

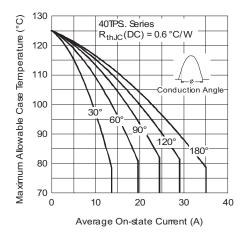


Fig. 1 - Current Rating Characteristics

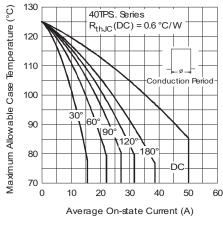


Fig. 2 - Current Rating Characteristics

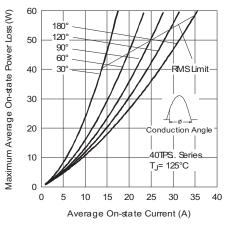


Fig. 3 - On-State Power Loss Characteristics

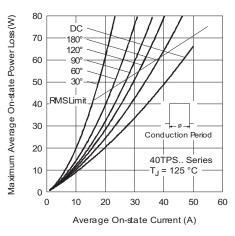


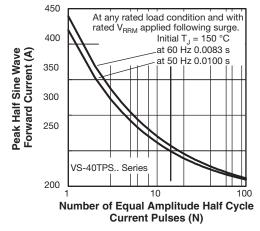
Fig. 4 - On-State Power Loss Characteristics

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Fig. 5 - Maximum Non-Repetitive Surge Current

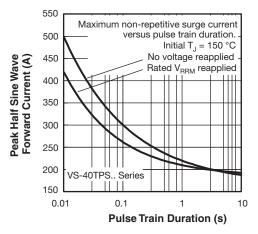


Fig. 6 - Maximum Non-Repetitive Surge Current

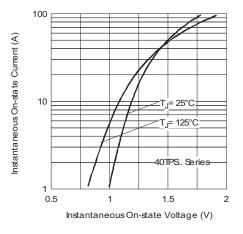


Fig. 7 - On-State Voltage Drop Characteristics

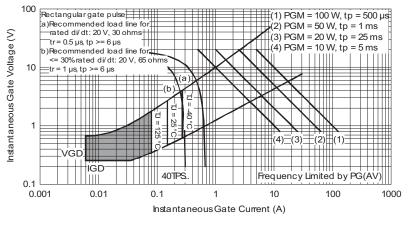


Fig. 8 - Gate Characteristics



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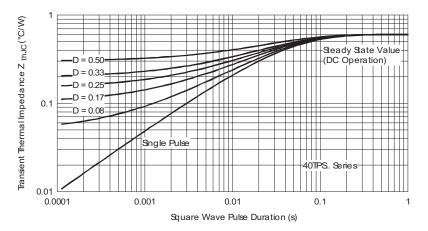


Fig. 9 - Thermal Impedance Z_{thJC} Characteristics

ORDERING INFORMATION TABLE

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Device code	VS-	40	т	Р	S	16	PbF
		(2)	(3)	4	(5)	(6)	(7)
							\bigcirc
	1 - 2 -			ng (40 =	tors pro	duct	
	3 -			iguratior	,		
		T =	Thyristo	or			
	4 -		kage:				
			TO-247				
	5 -		e of silio Standai		ery recti	fier	
	6 -				: 1600 V		
	7 -	Envi	ronmen	tal digit:			
		PbF	= Lead	(Pb)-fre	e and R	oHS co	mpliant
		-M3	= Halog	en-free,	RoHS	complia	nt, and

ORDERING INFORMATION (Example)									
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION						
VS-40TPS16PbF	25	500	Antistatic plastic tubes						
VS-40TPS16-M3	25	500	Antistatic plastic tubes						

LINKS TO RELATED DOCUMENTS							
Dimensions		www.vishay.com/doc?95542					
Dout moulting information	TO-247AC PbF	www.vishay.com/doc?95226					
Part marking information	TO-247AC -M3	www.vishay.com/doc?95007					

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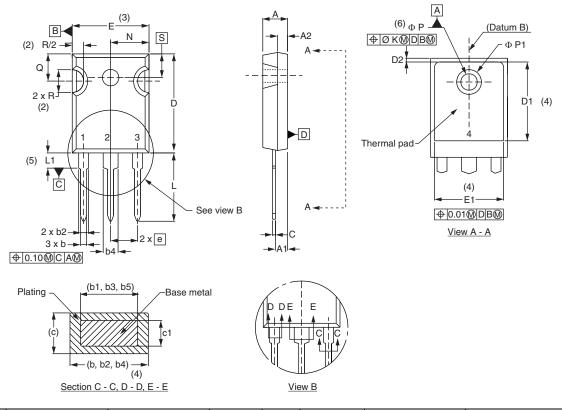
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TO-247 - 50 mils L/F

DIMENSIONS in millimeters and inches



	MILLIM	MILLIMETERS		HES	NOTES		SYMBOL	MILLIMETERS		INCHES		NOTES
STMBOL	MIN.	MAX.	MIN.	MAX.	NOTES		STNDOL	MIN.	MAX.	MIN.	MAX.	NOTES
A	4.65	5.31	0.183	0.209			D2	0.51	1.35	0.020	0.053	
A1	2.21	2.59	0.087	0.102			Е	15.29	15.87	0.602	0.625	3
A2	1.17	1.37	0.046	0.054			E1	13.46	-	0.53	-	
b	0.99	1.40	0.039	0.055			е	5.46	BSC	0.215	BSC	
b1	0.99	1.35	0.039	0.053			ØК	0.2	254	0.0)10	
b2	1.65	2.39	0.065	0.094			L	14.20	16.10	0.559	0.634	
b3	1.65	2.34	0.065	0.092			L1	3.71	4.29	0.146	0.169	
b4	2.59	3.43	0.102	0.135			N	7.62	BSC	0.3		
b5	2.59	3.38	0.102	0.133			ØР	3.56	3.66	0.14	0.144	
С	0.38	0.89	0.015	0.035			Ø P1	-	7.39	-	0.291	
c1	0.38	0.84	0.015	0.033			Q	5.31	5.69	0.209	0.224	
D	19.71	20.70	0.776	0.815	3		R	4.52	5.49	0.178	0.216	
D1	13.08	-	0.515	-	4		S	5.51	BSC	0.217	BSC	

Notes

⁽¹⁾ Dimensioning and tolerancing per ASME Y14.5M-1994

(2) Contour of slot optional

(3) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body

(4) Thermal pad contour optional with dimensions D1 and E1

⁽⁵⁾ Lead finish uncontrolled in L1

⁽⁶⁾ Ø P to have a maximum draft angle of 1.5 to the top of the part with a maximum hole diameter of 3.91 mm (0.154")

⁽⁷⁾ Outline conforms to JEDEC[®] outline TO-247 with exception of dimension c and Q

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